

# Phase Transitions in Lanthanum-Doped Strontium Bismuth Tantalate

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The effect of lanthanum substitution for bismuth in the Aurivillius phase,  $\text{SrBi}_{2-x}\text{La}_x\text{Ta}_2\text{O}_9$  ( $x = 0, 0.01, 0.02, 0.05, 0.1, 0.15$ , and  $0.2$ ) has been investigated. Increasing La concentration decreased the ferroelectric–paraelectric ( $A_{21am}$ – $A_{mam}$ ) transformation temperature until by  $x = 0.15$ , the material was paraelectric at room temperature. The transformation from  $A_{21am}$  to  $A_{mam}$  ( $T_{A_{21am}}$ ) was difficult to observe by neutron and X-ray diffraction but could be monitored using Raman spectroscopy for which unique modes associated with the loss of centrosymmetry were identified in the ferroelectric phase. Although the effect of La substitution for Bi on the  $I4/mmm$ – $A_{mam}$  ( $T_{Amam}$ ) phase transition is difficult to monitor, the intensity of the superstructure reflections in ED patterns obtained at room temperature remained qualitatively similar regardless of La concentration. La substitution was therefore considered to expand the  $T_{Amam}$ – $T_{A_{21am}}$  temperature interval.

## Introduction

Strontium bismuth tantalate (SBT) is a member of the Aurivillius family  $^{1-3}$  of layered ceramics  $(\text{Bi}_2\text{O}_2)^{2+}[\text{A}_{n-1}\text{B}_n\text{O}_{3n+1}]$ , for which  $n = 2$ .<sup>4,5</sup> Aurivillius layered materials may be considered as alternating layers of strontium bismuth tantalate  $\text{SrTa}_2\text{O}_7^{2-}$  perovskite blocks interleaved with layers of  $\text{Bi}_2\text{O}_2^{2+}$ . SBT is ferroelectric at room temperature with  $A_{21am}$  symmetry but on heating to  $>573$  K it undergoes a continuous transition to a paraelectric  $A_{mam}$ <sup>6</sup> phase and at  $\sim 823$  K<sup>7</sup> it undergoes a transition to the prototype  $I4/mmm$  phase. Schematics of the crystal structure are shown in Figure 1. Essentially, the  $A_{21am}$  phase is noncentrosymmetric with parallel cation displacements giving rise to spontaneous polarization that are coupled to in-phase rotations of the O octahedra around the  $b$  and  $c$  axes, whereas the  $A_{mam}$  phase is centrosymmetric with in phase rotations of O octahedra only around the  $b$  axis. The  $I4/mmm$  phase is the prototype structure which is centrosymmetric and untilted. The in-phase rotations in the  $A_{mam}$  and  $A_{21am}$  phases double the unit cell with respect to  $I4/mmm$  but despite a difference in symmetry the reflection conditions for  $A_{mam}$  and  $A_{21am}$  are identical.<sup>6,7</sup> The presence of intermediate paraelectric phases with doubled unit cells in Aurivillius compounds was first established by Reaney et al.<sup>8</sup> using in situ electron diffraction in strontium bismuth titanate ceramics. Subsequently, Hervoches and Lightfoot<sup>7</sup> used high-temperature neutron data to refine an  $A_{mam}$  cell in  $\text{SrBi}_2\text{Ta}_2\text{O}_9$ .

Previous studies<sup>9</sup> have demonstrated that SBT has a high remanent polarization, low coercive field, and an absence of ferroelectric fatigue. Such properties make SBT an ideal candidate for nonvolatile ferroelectric memories (NVFRAM).<sup>10,11</sup> As a result, extensive research has been undertaken using a combination of neutron diffraction at variable temperature,<sup>12–14</sup> electron microscopy, and Raman spectroscopy<sup>5</sup> to determine structure–property relations in this system. Macquart et al.<sup>12</sup> confirmed the existence of the  $A_{mam}$  phase at temperatures above 650 K, but has suggested that there is a continuous transition to  $I4/mmm$  symmetry between 650 and 800 K. The presence of a distorted phase at temperatures higher than 650 K was also confirmed by Kamba et al.<sup>15</sup> who observed ferroelastic domains in strontium bismuth tantalate up to 770 K.

Doping with lanthanide ( $\text{Ln}^{3+}$ ) ions has been investigated but commonly, substitution for Sr has been attempted in order to donor dope SBT in a manner reminiscent of soft

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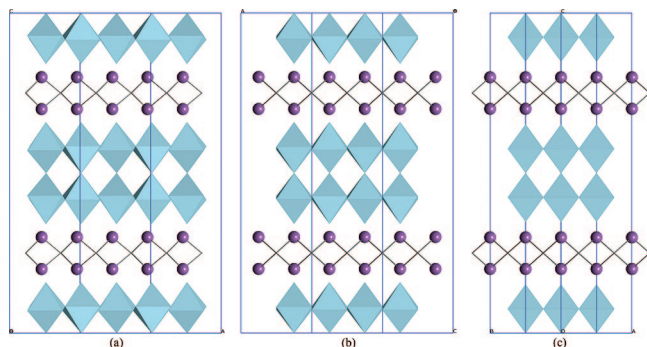
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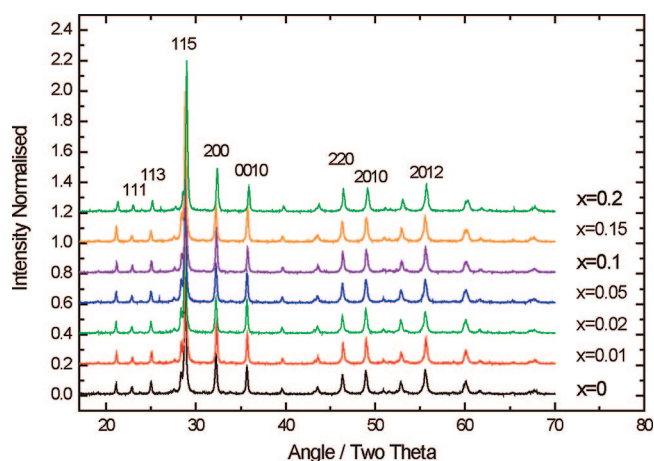
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**Figure 1.** Unit cell images of  $\text{SrBi}_2\text{Ta}_2\text{O}_9$  with (a)  $A2_1am$ , (b)  $Amam$ , and (c)  $I4/mmm$  symmetries along the  $[100]$  direction. The polyhedra indicate the  $\text{TaO}_6$  octahedra; the  $\text{Bi}_2\text{O}_2$  layers are shown as ions.



**Figure 2.** X-ray diffraction patterns recorded from calcined powders. No second phases are observed and there is no significant difference between the spectra.

$\text{Pb}(\text{Zr},\text{TiO})_3$ .<sup>16–19</sup> This mechanism has been shown to lower the ferroelectric  $T_c$  from  $\sim 300$  to  $180$  °C when, e.g.,  $\text{Sr}^{2+}$  was exchanged<sup>20</sup> with  $\text{Pr}^{3+}$ . The aim of this current work is to examine the effects of doping for  $\text{Bi}^{3+}$  with isovalent  $\text{La}^{3+}$  using the substitutional formula,  $\text{SrBi}_{2-x}\text{La}_x\text{Ta}_2\text{O}_9$ . The ceramics were examined using electron microscopy, neutron diffraction and variable-temperature Raman spectroscopy in order to provide complementary information about the structure and allow more complete interpretation of the dielectric and ferroelectric properties.

### Experimental Section

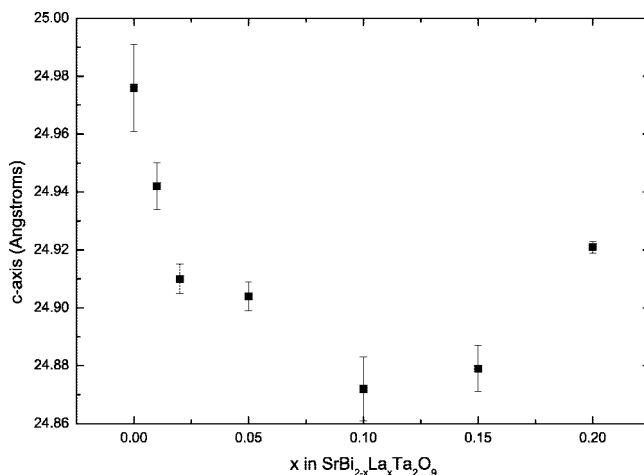
Samples were prepared by the calcination of stoichiometric amounts of  $\text{SrCO}_3$  (99%, Aldrich),  $\text{Bi}_2\text{O}_3$  (99.5%, Aldrich),  $\text{Ta}_2\text{O}_5$  (99.9%, Aldrich), and  $\text{La}_2\text{O}_3$  (99.5%, Aldrich). The powders were ball-milled using yttrium-stabilized zirconia milling media in acetone for 24 h. The powders were then dried and pressed into pellets. The pellets were heated at  $1100$  °C for 24 h at a heating

**Table 1.** Unit-Cell Parameters Derived from X-ray Powder Diffraction Data (Errors in the Final Digit Are Shown in Brackets)

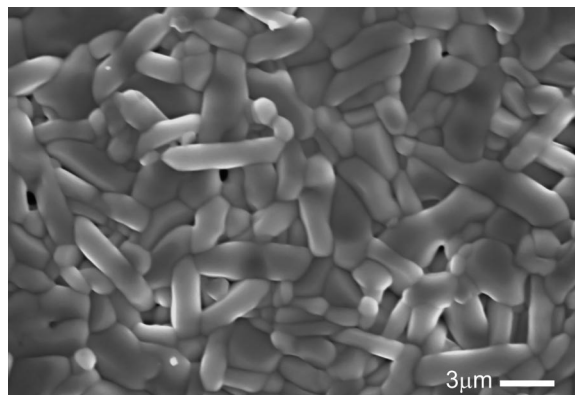
composition	$a$ (Å)	$b$ (Å)	$c$ (Å)	$V$ (Å <sup>3</sup> )
$\text{SrBi}_2\text{Ta}_2\text{O}_9$	5.510(5)	5.500(7)	24.976(15)	756.9(18)
$\text{SrBi}_{1.99}\text{La}_{0.01}\text{Ta}_2\text{O}_9$	5.499(5)	5.490(10)	24.942(8)	752.9(23)
$\text{SrBi}_{1.98}\text{La}_{0.02}\text{Ta}_2\text{O}_9$	5.499(4)	5.491(6)	24.910(5)	752.2(15)
$\text{SrBi}_{1.95}\text{La}_{0.05}\text{Ta}_2\text{O}_9$	5.500(5)	5.491(8)	24.904(5)	752.1(19)
$\text{SrBi}_{1.90}\text{La}_{0.1}\text{Ta}_2\text{O}_9$	5.492(5)	5.494(3)	24.872(11)	750.5(14)
$\text{SrBi}_{1.85}\text{La}_{0.15}\text{Ta}_2\text{O}_9$	5.511(2)	5.496(2)	24.879(8)	753.5(9)
$\text{SrBi}_{1.80}\text{La}_{0.20}\text{Ta}_2\text{O}_9$	5.511(5)	5.495(5)	24.921(2)	754.7(15)

rate of  $5 \text{ K min}^{-1}$ , ground into fine powder using the same milling media in acetone and dried. Once dried the powders were pressed into pellets and sintered at  $1150$  °C for 12 h. After cooling the samples were polished using diamond to a  $1 \mu\text{m}$  level. The density of the samples was found to be  $>95\%$  by the application of Archimedes's principle.

To confirm phase assemblage, samples were examined as powders using a Siemens D500 powder diffractometer with weighted Cu K-alpha radiation ( $1.5418 \text{ Å}$ ) and graphite monochromator. The patterns were collected over an angular range of  $5$ – $70^\circ$  with a step size of  $0.02$  degrees and a  $1 \text{ s}$  per step counting rate. Grain structures from freshly prepared fracture surfaces were examined using a CAMSCAN Mk2 electron microscope using secondary electron emission and an accelerating voltage of  $20 \text{ kV}$ . The microstructure was further examined using a Philips EM430 transmission electron microscope with an accelerating voltage of  $300 \text{ kV}$ . Samples were ground to  $25 \mu\text{m}$  and then thinned to electron transparency using a Gatan Duo Mill ion-beam thinner.



**Figure 3.** Plot of  $c$ -axis length against  $x$  in  $\text{SrBi}_{2-x}\text{La}_x\text{Ta}_2\text{O}_9$ , data shown in Table 1.



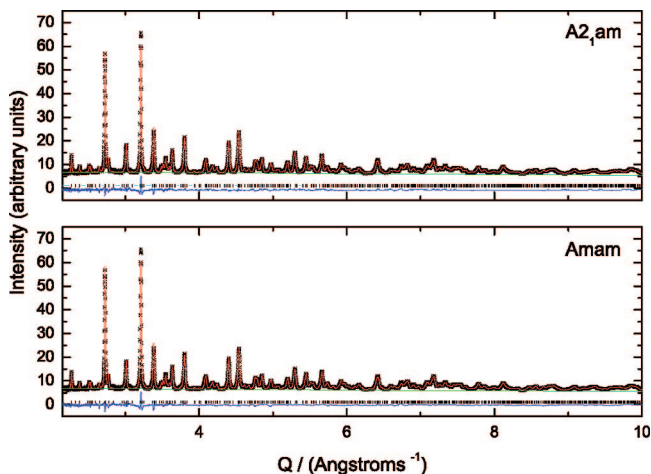
**Figure 4.** Secondary electron image from  $\text{SrBi}_{1.9}\text{La}_{0.1}\text{Ta}_2\text{O}_9$  showing the elongated grains, typical of these systems.

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**Table 2. Results from the Refinement of SrBi<sub>1.8</sub>La<sub>0.2</sub>Ta<sub>2</sub>O<sub>9</sub><sup>a</sup>**

Wyckoff		x	y	z	100U <sub>iso</sub>	frac
name	site					
Amam <sup>b</sup>						
Sr	4a	0.75	0.7491(9)	0.000000	0.71(4)	0.841(47)
Bi	4a	0.75	0.7491(9)	0.000000	0.71(4)	0.143(43)
La	4a	0.75	0.7491(9)	0.000000	0.71(4)	0.016(5)
Sr	8b	0.75	0.2645(6)	0.29889(6)	1.98(4)	0.080(24)
Bi	8b	0.75	0.2645(6)	0.29889(6)	1.98(4)	0.828(21)
La	8b	0.75	0.2645(6)	0.29889(6)	1.98(4)	0.092(2)
Ta	8b	0.75	0.2458(6)	0.08515(5)	0.296(17)	1.0000
O1	4a	0.75	0.2883(8)	0.000000	1.087(70)	1.0000
O2	8b	0.75	0.1935(5)	0.15838(11)	1.773(57)	1.0000
O3	8b	0.0	0.0	0.74955(11)	0.878(26)	1.0000
O4	8b	0.0	0.0	0.93072(7)	0.730(31)	1.0000
O5	8b	0.0	0.0	0.41693(10)	1.555(38)	1.0000
A2 <sub>1</sub> am <sup>c</sup>						
Sr	4a	0.0504(22)	0.2494(9)	0.000000	0.89(4)	0.764(47)
Bi	4a	0.0504(22)	0.2494(9)	0.000000	0.89(4)	0.213(42)
La	4a	0.0504(22)	0.2494(9)	0.000000	0.89(4)	0.024(5)
Sr	8b	0.5469(18)	0.7652(6)	0.20109(6)	2.06(5)	0.118(23)
Bi	8b	0.5469(18)	0.7652(6)	0.20109(6)	2.06(5)	0.794(21)
La	8b	0.5469(18)	0.7652(6)	0.20109(6)	2.06(5)	0.088(2)
Ta	8b	0.5486(14)	0.7465(5)	0.41464(6)	0.350(22)	1.0000
O1	4a	0.0624(25)	0.7121(9)	0.000000	0.873(79)	1.0000
O2	8b	0.5291(16)	0.6976(7)	0.34216(10)	1.725(61)	1.0000
O3	8b	0.8025(22)	0.0032(16)	0.25060(10)	0.849(31)	1.0000
O4	8b	0.7995(15)	0.9987(13)	0.06933(7)	0.709(34)	1.0000
O5	8b	0.817760	0.9823(10)	0.58332(9)	1.064(47)	1.0000

<sup>a</sup> Models use Amam and A2<sub>1</sub>am space group symmetry, respectively. The errors in the final digits are given in the brackets and are the esd's reported by GSAS. The  $wR_p$  and  $R_p$  values obtained from refinement using a model based on I4/mmm were 0.0393 and 0.0403, indicating poorer refinement than the models above. <sup>b</sup> SrBi<sub>1.8</sub>La<sub>0.2</sub>Ta<sub>2</sub>O<sub>9</sub>;  $wR_p$  = 0.0183,  $R_p$  = 0.0257. <sup>c</sup> SrBi<sub>1.8</sub>La<sub>0.2</sub>Ta<sub>2</sub>O<sub>9</sub>;  $wR_p$  = 0.0172,  $R_p$  = 0.0248.

**Figure 5.** Graphical results from the refinement of the recorded neutron data using A2<sub>1</sub>am and Amam symmetries as model.

Variable-temperature capacitance and dielectric loss measurements were collected using a HP 4284a LCR meter at 1, 10, 100, 250, and 1000 kHz, between 10K and 1073K. At temperatures below 300 K, an Oxford Instruments 1020 Cryocooler and above 300 K a Carbolite tube furnace were used to control the temperature.

Polarization-electric field (P-E) hysteresis loops were recorded with a computer controlled modified Sawyer–Tower circuit supplied with sinusoidal electric field of 50 Hz. The maximum electric field that could be applied was 4 kV, and all measurements were carried out at 298K on thinned samples.

Raman spectra were collected using a Renishaw InVia microscope with an incident radiation of 514.5 nm, coupled with a Rencam CCD detector operating in back-scattered geometry. Samples were collected at both room temperature, and at variable temperature in the range –60 to 180 °C, using a Linkam cooling/heating stage with optically flat glass windows. The CCD detector

**Table 3. Bond Valence Summations ( $S_{ij}$ ) for SrBi<sub>1.8</sub>La<sub>0.2</sub>Ta<sub>2</sub>O<sub>9</sub> Using Amam and A2<sub>1</sub>am Symmetries<sup>a</sup>**

model	site	fraction	length	error	no.	$S_{ij}$	error
Amam	A, Sr/Bi/La–O	0.841/0.143/0.016	2.548	0.006	1		
			2.982	0.006	1		
			2.7707	0.005	2		
			2.6142	0.0027	4		
			2.8493	0.003	4	2.334	0.021
	B, Bi/Sr/La–O	0.828/0.080/0.092	2.9715	0.0012	2		
			2.602	0.004	1		
			2.3482	0.0025	2		
	C, Ta–O	1	2.2641	0.0024	2	2.741	0.019
			2.142	0.0015	1		
A2 <sub>1</sub> am	A, Sr/Bi/La–O	0.764/0.213/0.024	1.8537	0.0033	1		
			1.9783	0.0022	2		
			1.9713	0.0022	2	5.195	0.033
			2.972	0.007	1		
			2.559	0.007	1		
	B, Bi/Sr/La–O	0.794/0.118/0.088	2.705	0.013	1		
			2.837	0.012	1		
			2.617	0.007	2		
			2.604	0.008	2		
			2.766	0.006	2	2.336	0.049
	C, Ta–O	1	2.953	0.006	2		
			2.883	0.009	1		
			2.626	0.005	1		
			2.293	0.008	1		
			2.235	0.005	1		
	D, Sr/Bi/La–O	0.764/0.213/0.024	2.342	0.009	1		
			2.357	0.008	1	2.679	0.052
			2.148	0.0015	1		
			1.8352	0.0033	1		
			1.973	0.008	1		
	E, Ta–O	1	1.99	0.008	1		
			1.969	0.009	1		
			1.979	0.009	1	5.220	0.092

<sup>a</sup> The summations are in close agreement with each other and are both indicative of reliable refinements.

decreases in efficiency below 200 cm<sup>–1</sup>, with an observed decrease in intensity the lower the shift, thus preventing some modes from being visible in the spectra.

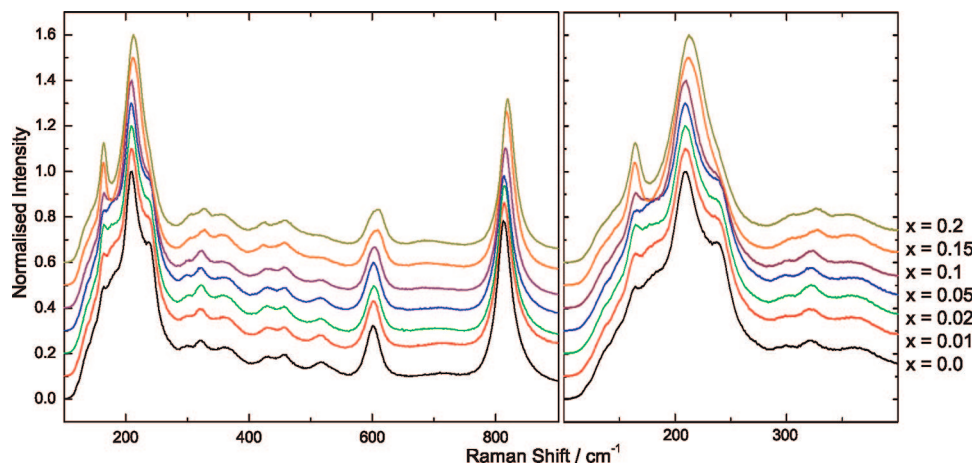
Time-of-flight powder neutron diffraction data were collected on SrBi<sub>2</sub>Ta<sub>2</sub>O<sub>9</sub> and SrBi<sub>1.8</sub>La<sub>0.2</sub>Ta<sub>2</sub>O<sub>9</sub> using the POLARIS diffractometer at the UK pulsed spallation neutron source ISIS, Rutherford Appleton Laboratory.<sup>21,22</sup> For each composition studied, approximately 10 g of powdered sample were loaded into a thin-walled, cylindrical vanadium sample can and diffraction data collected for between ~185  $\mu$ A h (equivalent to ~1 h of neutron beamtime). Summed and normalized data collected in backscatter bank C (high resolution bank) over the time-of-flight range ~2000 to 19 995  $\mu$ s (corresponding to a range in Q of ~2.15 to 11.2  $\text{\AA}^{-1}$ ) were analyzed by the Rietveld Method using the GSAS suite of software<sup>23</sup> with the EXPGUI toolkit.<sup>24</sup>

## Results and Discussion

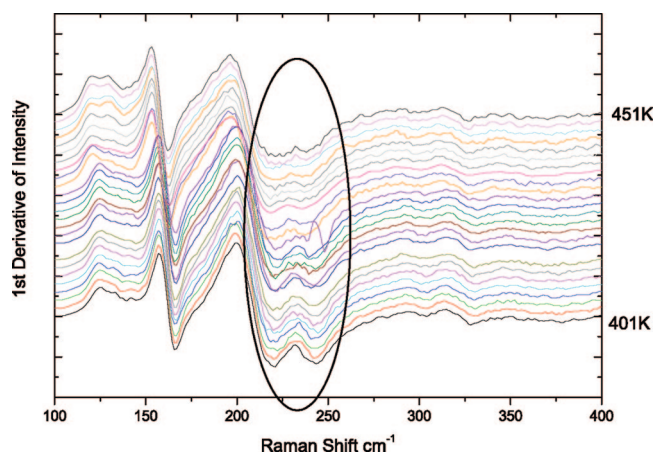
**Structural and Microstructural Characterization. X-Ray Diffraction and Scanning Electron Microscopy.** X-ray powder diffraction traces, shown in Figure 2, collected from the synthesized powders before sintering did not reveal the presence of any second phases and all peaks could be indexed

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**Figure 6.** Room-temperature Raman spectra collected from the series  $\text{SrBi}_{2-x}\text{La}_x\text{Ta}_2\text{O}_9$  with  $x = 0.0, 0.01, 0.02, 0.05, 0.1, 0.15$ , and  $0.2$ . The spectra have been normalized to the peak at  $210\text{ cm}^{-1}$  the plot on the left is the complete range of data collected and the plot on the right is a magnification of the region  $100\text{--}400\text{ cm}^{-1}$  more clearly illustrating the change in from  $A2_1\text{am}$  to  $\text{Amam}$  symmetry as  $x$  increases.



**Figure 7.** Variable-temperature Raman spectra recorded for  $\text{SrBi}_{1.9}\text{La}_{0.1}\text{Ta}_2\text{O}_9$ . The data have been plotted as the first derivative to highlight the change from  $A2_1\text{am}$  to  $\text{Amam}$  symmetry.

using an orthorhombic cell of an  $n = 2$  Aurivillius compound with A-centered symmetry, i.e.  $A2_1\text{am}$  or  $\text{Amam}$ . The unit-cell parameters of all synthesized compounds are listed in Table 1. The lattice parameters do not vary significantly with  $x$  since the ionic radius of  $\text{La}^{3+}$  is close to that of  $\text{Bi}^{3+}$  ( $\sim 0.13\text{ nm}^{25,26}$ ) in similar co-ordination. However, the unit cell volume decreases marginally from  $0 < x < 0.1$  and increases at  $x > 0.1$ , Figure 3. Non linearity in the unit-cell volume vs  $x$  indicates that the system does not conform to Vegard's law and that there is a phase transition, presumably from  $A2_1\text{am}$  to  $\text{Amam}$ , at  $x \approx 0.1$ .

Scanning electron microscopy of freshly fractured sintered pellets showed the grain structure to be consistent with a high density. An example image is shown in Figure 4. The acicular grains are typical of the crystal morphology expected for an orthorhombic layer-structure in which the  $c$  (layered axis) constitutes a more difficult growth direction compared with  $a$  and  $b$ . The average size of the grains was  $\sim 1\text{--}2\text{ }\mu\text{m}$

in the thinner  $c$ -direction and  $\sim 5\text{ }\mu\text{m}$  in the  $a$ - and  $b$ -directions.<sup>27</sup>

**Neutron Diffraction.** Rietveld refinements were carried out using two models based on  $A2_1\text{am}$  and  $\text{Amam}$  space group symmetry for neutron diffraction data from  $\text{SrBi}_2\text{Ta}_2\text{O}_9$  and  $\text{SrBi}_{1.8}\text{La}_{0.2}\text{Ta}_2\text{O}_9$  samples. These samples were chosen as it was anticipated that  $\text{SrBi}_2\text{Ta}_2\text{O}_9$  would refine as the  $A2_1\text{am}$  phase, typical of an  $n = 2$  ferroelectric Aurivillius compound whereas  $\text{SrBi}_{1.8}\text{La}_{0.2}\text{Ta}_2\text{O}_9$  was most likely to have the orthorhombic paraelectric, structure with  $\text{Amam}$  symmetry at room temperature. In the early stages of refinement a Le-Bail fit was used to determine the best space group symmetry match to the recorded data. However, this proved to be inadequate to confirm symmetry, as the conditions limiting possible reflections for both space groups are identical. To determine structure and therefore space group symmetry, full Rietveld refinement was undertaken using the unit-cell sizes, and peak profiles determined in the Le-Bail fit. The results from the refinement are shown in Table 2. Statistically, it is not easy to determine which model best describes the system under examination and when the differences between the models and the recorded data are compared they are well within the expected error. Examples of the graphical results from refinement are shown in Figure 5, illustrating the equivalency of fit for the  $\text{Amam}$  and the  $A2_1\text{am}$  space groups. The bond valence summations for both models are shown in Table 3.

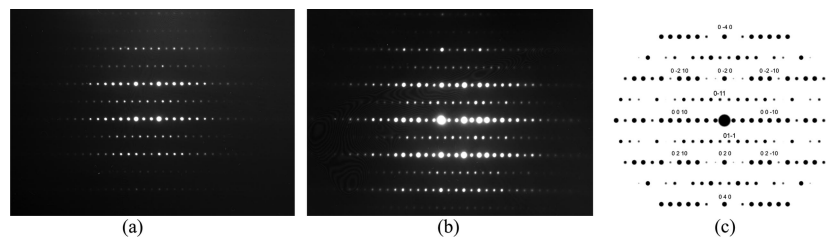
It was concluded therefore that refinements of neutron diffraction data from  $\text{SrBi}_{1.8}\text{La}_{0.2}\text{Ta}_2\text{O}_9$  and  $\text{SrBi}_2\text{Ta}_2\text{O}_9$  were insensitive to the small difference between the  $\text{Amam}$  and  $A2_1\text{am}$  symmetries. To differentiate between the two potential space groups, Raman spectroscopy was employed where it was anticipated that the loss of centrosymmetry on cooling through the  $\text{Amam}\text{--}A2_1\text{am}$  phase transition should result in new active modes.

**Raman Spectroscopy.** Raman spectra were collected as a function of composition across the  $\text{SrBi}_{2-x}\text{La}_x\text{Ta}_2\text{O}_9$ , Figure

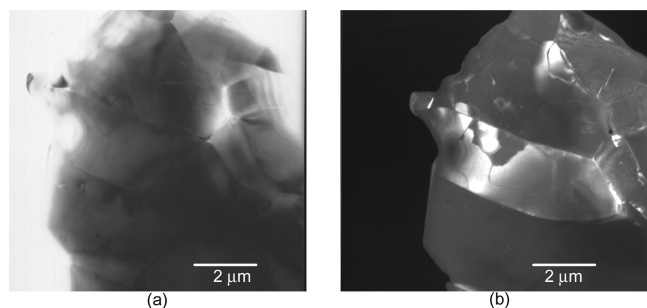
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**Figure 8.** Electron diffraction pattern from the [100] zone axis in (a)  $\text{SrBi}_2\text{Ta}_2\text{O}_9$  and (b)  $\text{SrBi}_{1.8}\text{La}_{0.2}\text{Ta}_2\text{O}_9$  showing an identical superstructure in each composition; (c) a simulated kinematical diffraction pattern with peaks indexed. Indexed positions are shown for 01 $\bar{1}$  and 0 $\bar{1}1$  superstructure reflections.



**Figure 9.** Transmission electron micrographs of  $\text{SrBi}_2\text{Ta}_2\text{O}_9$ , showing (a) a bright-field image the acicular grains and (b) a dark-field image taken obtained using the superlattice reflections arrowed in Figure 8; note the presence of orientational and translational domain variants.

**Table 4.** Change in Permittivity As Function of Lanthanide Concentration, Measured at 10 KHz (Errors in Measured Temperature Are Shown in Brackets)

composition	peak in permittivity (K)	relative permittivity at peak
$\text{SrBi}_2\text{Ta}_2\text{O}_9$	568(1)	360
$\text{SrBi}_{1.99}\text{La}_{0.01}\text{Ta}_2\text{O}_9$	555(1)	392
$\text{SrBi}_{1.98}\text{La}_{0.02}\text{Ta}_2\text{O}_9$	550(1)	290
$\text{SrBi}_{1.95}\text{La}_{0.05}\text{Ta}_2\text{O}_9$	510(1)	250
$\text{SrBi}_{1.90}\text{La}_{0.1}\text{Ta}_2\text{O}_9$	410(1)	270
$\text{SrBi}_{1.85}\text{La}_{0.15}\text{Ta}_2\text{O}_9$	246(2)	210
$\text{SrBi}_{1.80}\text{La}_{0.20}\text{Ta}_2\text{O}_9$	170(2)	135

6. Using the software previously published by Kroumova et al.,<sup>28</sup> SAM, it is possible to predict the potential modes for each of the 3 known symmetries adopted by  $\text{SrBi}_2\text{Ta}_2\text{O}_9$ .

$$\text{A2}_1\text{am: } 22\text{A}_1 + 20\text{A}_2 + 20\text{B}_1 + 22\text{B}_2 \quad \text{total } 84$$

$$\text{Amam: } 11\text{A}_{1g} + 13\text{B}_{1g} + 9\text{B}_{2g} + 8\text{B}_{3g} \quad \text{total } 41$$

$$\text{I4/mmm: } 4\text{A}_{1g} + 2\text{B}_{1g} + 6\text{E}_g \quad \text{total } 12$$

The difference in the number of Raman active modes in between  $\text{A2}_1\text{am}$  and  $\text{Amam}$  is 43. However, it is well-known that many such modes will overlap and the practical differences in recorded spectra from  $\text{Amam}$  and  $\text{A2}_1\text{am}$  phases may well be slight. In this study, no attempt was made at precise mode assignment for the two orthorhombic phases. Some references are made to assignments based on the I4/mmm cell by previous researchers,<sup>5,29</sup> but in general, a comparative approach was utilized as a function of temperature and composition to determine the onset of the  $\text{A2}_1\text{am}$ – $\text{Amam}$  phase transition. It should be noted that

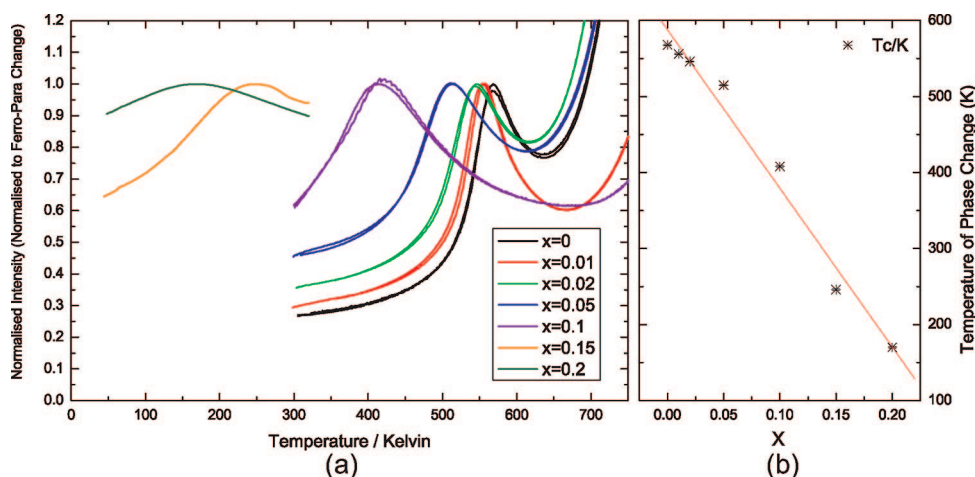
bands at 167 and 181  $\text{cm}^{-1}$  have lower intensities than anticipated because of detector efficiency decreasing below 200  $\text{cm}^{-1}$ . Using the I4/mmm unit cell as a basis,<sup>5,29</sup> it is possible to assign modes to some of the observable peaks. The band at 160  $\text{cm}^{-1}$  is assigned to an  $\text{A}_{1g}$  mode present in phases which are centrosymmetric, i.e.,  $\text{Amam}$  and I4/mmm.  $\text{E}_g$  modes, present in I4/mmm symmetry, between 200 and 400  $\text{cm}^{-1}$  split to lower symmetry modes (A and B) in the  $\text{A2}_1\text{am}$  and  $\text{Amam}$  structures. These are likely to be from the  $\text{Bi}_2\text{O}_7^{2+}$  layers within the structure. Ta–O octahedral  $\text{A}_{1g}$  modes,  $\text{A}_1$  when  $\text{A2}_1\text{am}$  symmetry is adopted, give rise to bands at 600 and 810  $\text{cm}^{-1}$ . The peak position of the  $\text{TaO}_6$  at 810  $\text{cm}^{-1}$  increased from 812  $\text{cm}^{-1}$  for  $\text{SrBi}_2\text{Ta}_2\text{O}_9$  to 819  $\text{cm}^{-1}$  for  $\text{SrBi}_{1.8}\text{La}_{0.2}\text{Ta}_2\text{O}_9$ , presumably related to the decrease in ionic mass of the A-site in the perovskite blocks as La substitutes for Bi. Most importantly, the observation that the centrosymmetric,  $\text{A}_{1g}$  band at 160  $\text{cm}^{-1}$  increases sharply in intensity between two incremental lanthanum concentrations ( $x = 0.1$  and  $x = 0.15$ ), while at the same time the shoulder at 240  $\text{cm}^{-1}$  disappears is characteristic of a change in symmetry, presumably between  $\text{A2}_1\text{am}$  and  $\text{Amam}$ . The observation of a change in symmetry at  $x \approx 0.1$  is consistent with the trends in unit cell volume shown in Figure 3.

Variable-temperature measurements were recorded for  $\text{SrBi}_{1.9}\text{La}_{0.1}\text{Ta}_2\text{O}_9$ , and  $\text{SrBi}_{1.85}\text{La}_{0.15}\text{Ta}_2\text{O}_9$  through the expected  $\text{A2}_1\text{am}$ – $\text{Amam}$  phase transition, a plot of the first derivative of the recorded for  $\text{SrBi}_{1.9}\text{La}_{0.1}\text{Ta}_2\text{O}_9$  is shown in Figure 7. The first derivative of the data is presented as it highlights the subtle changes in peak shape that arise from the change in symmetry between  $\text{Amam}$  and  $\text{A2}_1\text{am}$ . As temperature increases, a transition is observed at  $\sim 420$  and  $\sim 250$  K for  $x = 0.1$  and 0.15, respectively, similar to that obtained from the  $\text{SrBi}_{2-x}\text{La}_x\text{Ta}_2\text{O}_9$  as a function of composition.

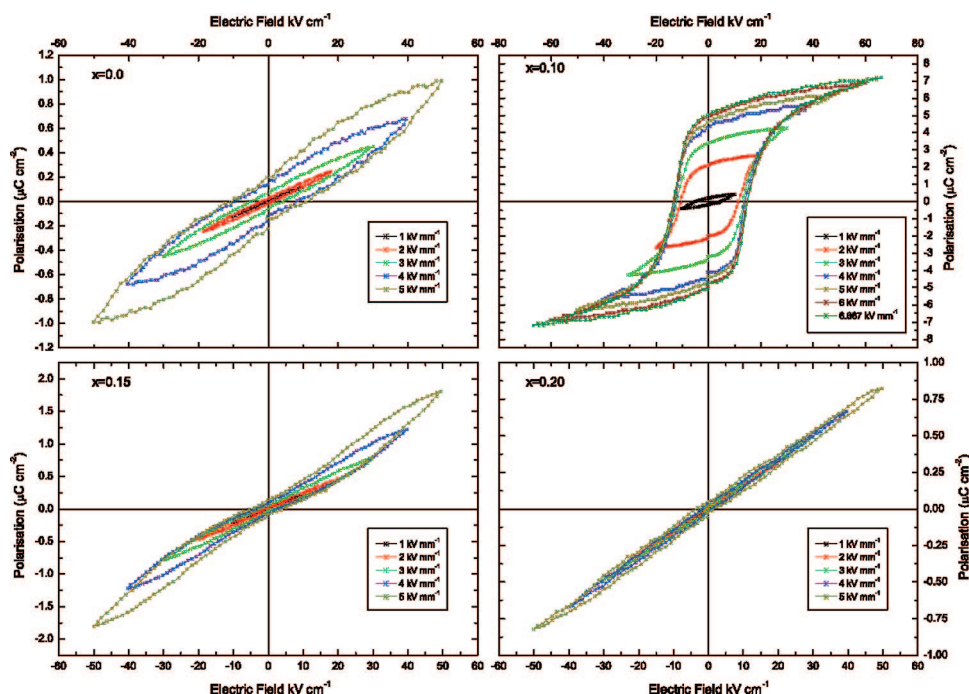
**Transmission Electron Microscopy.** Figure 8 shows the electron diffraction patterns with the beam parallel with a  $[010]_o$  of  $\text{SrBi}_2\text{Ta}_2\text{O}_9$  and  $\text{SrBi}_{1.8}\text{La}_{0.2}\text{Ta}_2\text{O}_9$ . The patterns in each case are identical and can be indexed according to an A-centered orthorhombic cell (either  $\text{Amam}$  or  $\text{A2}_1\text{am}$ ) with the approximate lattice parameters listed in Table 1. Superstructure reflections arising from the unit cell doubling are arrowed and have qualitatively similar intensities in each case. Figure 9 shows a bright field TEM image of several grains in a  $\text{SrBi}_2\text{Ta}_2\text{O}_9$  and the associated dark field image obtained using the systematic row of superstructure reflections of arrowed in Figure 8. The highlighted grain contains bright and dark regions which correspond to twin  $[010]_o$  and  $[100]_o$  90° domain variants, respectively of the orthorhombic structure. Additionally, within the bright  $[010]_o$  variant,

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**Figure 10.** (a) Normalized plots of permittivity versus temperature for different values of  $x$  in  $\text{SrBi}_{2-x}\text{La}_x\text{Ta}_2\text{O}_9$ , where the peak corresponds to the Amam to  $A2_1\text{am}$  phase transition; (b) phase transition temperature as a function of  $x$ .



**Figure 11.** Ferroelectric hysteresis loops recorded for  $\text{SrBi}_{2-x}\text{La}_x\text{Ta}_2\text{O}_9$  at 298 K.

ribbonlike planar defects are observed (arrowed) that correspond to antiphase boundaries that have formed when two out of phase tilted regions impinge. Similar planar defects were also observed for the  $\text{SrBi}_{1.8}\text{La}_{0.2}\text{Ta}_2\text{O}_9$  and similar images were observed for strontium bismuth titanate-based ceramics by Reaney et al.<sup>8,27</sup>

**Electrical Measurements. Relative Permittivity.** The relative permittivity as a function of temperature are shown in Table 4 and Figure 10. Substituting La for Bi has decreased the temperature of the ferroelectric–paraelectric phase transition ( $T_c$ ) from 568 to 170 K, at  $x = 0.2$  and the maximum permittivity ( $\epsilon_r(\text{max})$ ) from 360 to 135. The value of 568 K agrees with that previously published by Almeida et al.<sup>6</sup> who studied single crystals of  $\text{SrBi}_2\text{Ta}_2\text{O}_9$ . The decrease in  $T_c$  and the  $\epsilon_r(\text{max})$  is most likely linked to the replacement of highly polarizable  $\text{Bi}^{3+}$  cations with less-polarizable  $\text{La}^{3+}$ . At low La concentrations, a second weak anomaly in the permittivity as a function of temperature

could be observed between 850 and 950 K which may be related to the phase transition from Amam to  $I4_1\text{mmm}$ . However, the intensity of this peak reduced to zero as La concentration increased and could not therefore be used to monitor the onset of tilting in these samples.

**Ferroelectric Hysteresis.** Ferroelectric hysteresis loops recorded at room temperature for  $\text{SrBi}_2\text{Ta}_2\text{O}_9$ ,  $\text{SrBi}_{1.9}\text{La}_{0.1}\text{Ta}_2\text{O}_9$ ,  $\text{SrBi}_{1.85}\text{La}_{0.15}\text{Ta}_2\text{O}_9$ , and  $\text{SrBi}_{1.8}\text{La}_{0.2}\text{Ta}_2\text{O}_9$  are shown in Figure 11. Four characteristic types of loops are observed.  $\text{SrBi}_2\text{Ta}_2\text{O}_9$  to  $\text{SrBi}_{1.95}\text{La}_{0.05}\text{Ta}_2\text{O}_9$ , ( $T_c$  values of  $\sim 568$  and 510 K, respectively) did not exhibit saturated loops with evidence of only partial switching. For  $\text{SrBi}_{1.9}\text{La}_{0.1}\text{Ta}_2\text{O}_9$  with  $T_c \approx 410$  K, saturated hysteresis loops were obtained with a coercive field and remanent polarization of  $15 \text{ kV cm}^{-1}$  and  $5 \mu\text{C cm}^{-1}$ , respectively, both lower than those reported for undoped  $\text{SrBi}_2\text{Ta}_2\text{O}_9$ ,<sup>16</sup> possibly because of the reduction in spontaneous polarization by substituting  $\text{La}^{3+}$  for  $\text{Bi}^{3+}$ .  $\text{SrBi}_{1.85}\text{La}_{0.15}\text{Ta}_2\text{O}_9$  exhibits only partial switching



at room temperature. However, the  $\epsilon_r$  (max) is broad at  $\sim 246$  K with evidence that some of the sample is ferroelectric above room temperature. It is therefore suggested that part of the composition is ferroelectric at room temperature and is capable of being switched whereas a significant volume fraction of the sample is paraelectric.  $\text{SrBi}_{1.8}\text{La}_{0.2}\text{Ta}_2\text{O}_9$ ,  $T_c \approx 170$ , exhibits a linear increase in polarization with field typical of a paraelectric phase.

**General Discussion.**  $\text{La}^{3+}$  and  $\text{Bi}^{3+}$  have similar ionic sizes ( $\sim 0.13$  nm<sup>25,26</sup>) but their polarizabilities differ markedly with the lone pair  $\text{Bi}^{3+}$  ion being generally considered as ferroelectrically active in perovskites and related materials. Suarez et al.<sup>4</sup> empirically demonstrated that the tolerance factor for the perovskite blocks has a linear relationship with the onset temperature of  $T_c$  for a broad range of Sr, Ca, Ba, and Pb-based Aurivillius compounds. They postulated that the tolerance factor controlled the onset temperature of octahedral rotations in the Aurivillius family which in turn were strongly coupled to the spontaneous polarization. Hence, the anomalously high  $T_c$  of compounds such as  $\text{CaBi}_2\text{Nb}_2\text{O}_9$  and  $\text{Ca}_2\text{Bi}_4\text{Ti}_5\text{O}_{18}$  ( $> 1250$  K) in comparison to  $\text{Bi}_4\text{Ti}_3\text{O}_{12}$  ( $\sim 950$  K) could be rationalized. In the  $\text{SrBi}_{2-x}\text{La}_x\text{Ta}_2\text{O}_9$  series, tolerance factor effectively remains the same and only the average polarizability decreases with increasing La concentration. From the structural and electrical data presented, it is evident that  $T_c$  decreases with La concentration despite tolerance factor remaining largely constant in direct contrast to the crystallochemical plots first presented by Suarez et al.<sup>4</sup> Moreover, the Amam intermediate, tilted paraelectric, orthorhombic phase is still retained at room temperature even for  $\text{SrBi}_{1.8}\text{La}_{0.2}\text{Ta}_2\text{O}_9$ , whose  $T_c$  occurs at 170 K. It is evident therefore that the crystallochemical relationship between tolerance factor and  $T_c$  is not entirely related to the onset of octahedral tilting and is more complex than Suarez et al.<sup>4</sup> previously considered. In a recent publication, Hyatt et al.<sup>30</sup> reported that as  $T_c$  decreases the temperature interval between the onset of tilting ( $T_{\text{Amam}}$ ) and that of ferroelectricity ( $T_{\text{A21am}}$ ) increases with decreasing ferroelectric  $T_c$ . Therefore, the temperature dependence of  $T_{\text{Amam}}$  with composition is markedly different than that of  $T_{\text{A21am}}$ . One of the compelling arguments made

by Suarez et al.<sup>4</sup> is that if Ca, Sr, and Ba bismuth niobate and titanates are considered, the high  $T_c$  of, for example,  $\text{CaBi}_2\text{Nb}_2\text{O}_9$  and  $\text{Ca}_2\text{Bi}_4\text{Ti}_5\text{O}_{18}$ , may be explained only by the lower tolerance of factor of these compound and not on the polarizability and coordination of the constituent ions. Low  $t$  increases the onset temperature for tilt, which is coupled strongly to the onset of spontaneous polarization, and  $T_c$  increases. However, the increase in  $T_{\text{Amam}} - T_{\text{A21am}}$  demonstrated by Hyatt et al.<sup>30</sup> as  $T_c$  decreases indicates that coupling of the onset of tilting to the spontaneous polarization is significantly weaker as  $T_c$  decreases. Moreover, the data presented in this article shows that it can be completely decoupled by the substitution of La for Bi in the  $\text{SrBi}_{2-x}\text{La}_x\text{Ta}_2\text{O}_9$  series. The general relationship between  $T_c$  and tolerance factor illustrated by Suarez et al.<sup>4</sup> may therefore only apply for Aurivillius phases whose  $T_{\text{Amam}}$  and  $T_{\text{A21am}}$  are in close proximity and are able to couple. Such compounds invariably have high  $T_c$ . For lower  $T_c$  compounds, coupling is insignificant and  $T_c$  is more likely to be controlled by the average polarizability of the constituent ions in their requisite coordinations. Any relationship between tolerance factor and  $T_c$  for low  $T_c$  compounds is therefore coincidental.

## Conclusions

La-doped SBT compositions have been fabricated in which the ferroelectric phase transition ( $T_{\text{A21am}}$ ) decreased with increasing La concentration but the temperature of the octahedral tilt transition ( $T_{\text{Amam}}$ ) presumably remained largely unchanged. The data confirm that octahedral tilting and the onset of ferroelectricity are not strongly coupled in all Aurivillius compounds as previously postulated. Instead, coupling is proposed to be strong in high  $T_c$  compounds, with the onset of ferroelectricity enhanced in low  $t$  compounds such as  $\text{CaBi}_2\text{Nb}_2\text{O}_9$ , but becomes progressively weaker as  $T_c$  decreases accompanied by a commensurate increase in the temperature interval  $T_{\text{Amam}} - T_{\text{A21am}}$ . Any relationship between tolerance factor and  $T_c$  for low  $T_c$  compounds is therefore considered coincidental.

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